MSKSEMI 美森科







TVC



TOO



MOV



GDT



PIFF

PMBT3904MB(MS)

Product specification





Features

- Low profile package
- Ideal for automated placement
- Low saturation voltages
- High voltage capability
- High Stability and High Reliability
- RoHS Compliant

Applications

- amplifying signal
- Electronic switch
- Oscillating circuit
- Variable resistance
- Lighting applications

Appearance & Symbol

PACKAGE OUTLINE	Pin Configuration	Marking
1: Base 2: Emitter 3: Collector	Base	6P



Absolute Maximum Ratings (T=25℃ unless otherwise noted)

Parameter	Symbol	Value	Unit
Collector-Base Voltage	Vсво	60	V
Collector-Emitter Voltage	Vceo	40	V
Emitter-Base Voltage	VEBO	6	V
Collector Current Continuous	Ic	0.2	A
Power Dissipation	P _D	0.3	W
Operating Junction temperature	TJ	-55 to +150	°
Storage Temperature Range	T _{STG}	-55 to +150	$^{\circ}$

Electrical Characteristics (T=25℃ unless otherwise noted)

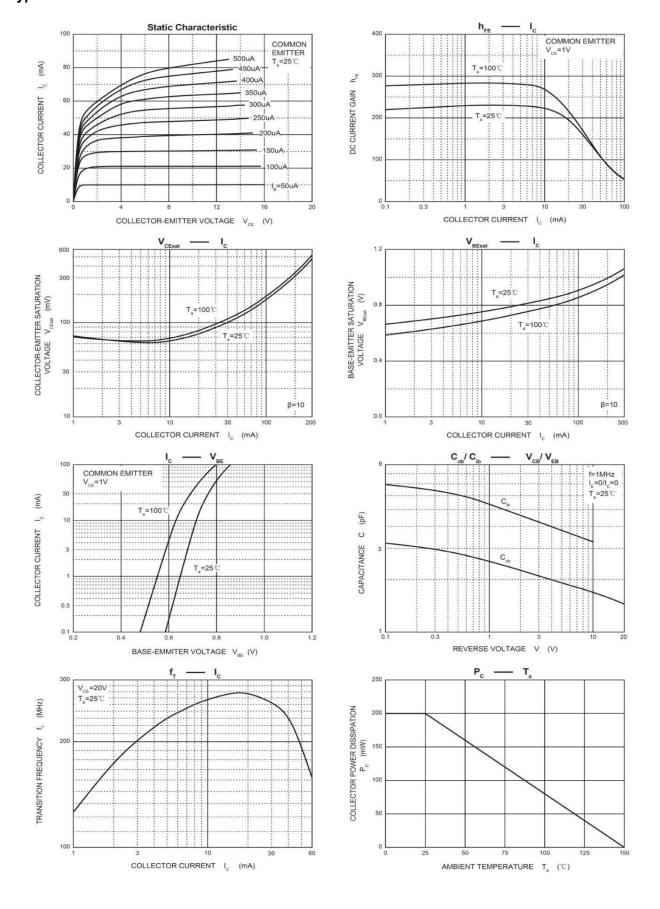
Parameter	Symbol	Test conditions	Min	Тур	Max	Unit
Collector-Base Breakdown Voltage	V _{CBO}	I _C =10μΑ, I _E =0	60			V
Collector-Emitter Breakdown Voltage	V _{CER}	I _C =1mA,I _B =0	40			V
Emitter-Base Breakdown Voltage	V _{EBO}	I _E =10uA,I _C =0	6			V
Collector Cut-Off Current	I _{CBO}	V _{CB} =60V, I _E =0			100	nA
Collector Cut-Off Current	I _{CEX}	V _{CE} =30V,V _{EB(off)} =3V			50	nA
Emitter Cut-Off Current	I _{EBO}	V _{EB} =5V,I _C =0			100	nA
DC current gain		V _{CE} =1V,I _C =0.1mA	40			
		V _{CE} =1V,I _C =1mA	70			
	h _{FE}	V _{CE} =1V,I _C =10mA	100		300	
		V _{CE} =1V,I _C =50mA	60			
		V _{CE} =1V,I _C =100mA	30			
Collector-emitter saturation voltage	V _{CE(sat)}	I _C =50mA, I _B =5mA			0.3	V
Base -emitter saturation voltage	V _{BE(sat)}	I _C =50mA, I _B =5mA			0.95	V
Transition frequency	f⊤	V _{CE} = 20V, I _C =10mA,f=100MHz	300			MHZ
Delay Time	td	V _{CC} =3V, I _C = 10mA,		35		
Rise time	tr	V _{BE(off)} =-0.5V, I _{B1} =1mA		35		ns
Storage time	ts	V _{CC} =3V, I _C =10mA,		200		us
Fall time	tf	$I_{B1} = I_{B2} = 1 \text{mA}$		50		ns

Classification of hee

Range	100-300
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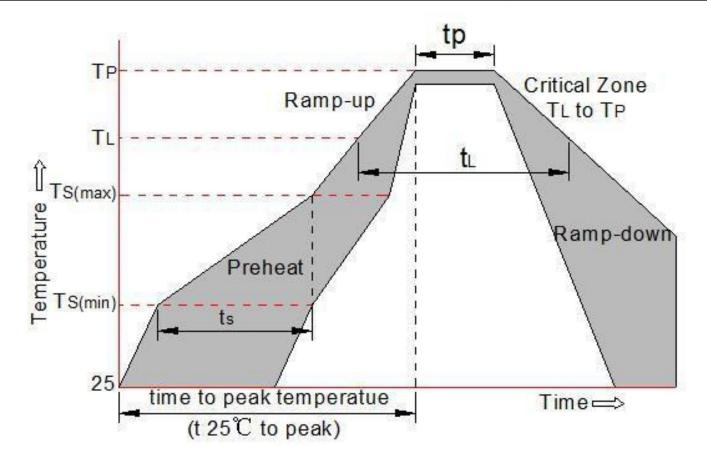
Typical Characteristics





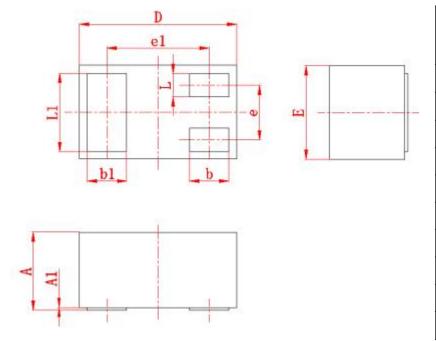
Soldering parameters

Reflow Condition		Pb-Free assembly (see as bellow)
	-Temperature Min (T _{s(min)})	+150℃
Pre Heat	-Temperature Max(T _{s(max)})	+200℃
T TO TIOUT	-Time (Min to Max) (ts)	60-180 secs.
Average	ramp up rate (Liquid us Temp (T _L) to peak)	3°C/sec. Max
	T _{s(max)} to T _L - Ramp-up Rate	
	-Temperature(T _∟) (Liquid us)	+217℃
Reflow	-Temperature(t∟)	60-150 secs.
	Peak Temp (T _p)	
Tir	Time within 5℃ of actual Peak Temp (t _p)	
Ramp-down Rate		6°C/sec. Max
Time 25℃ to Peak Temp (T _P)		8 min. Max
Do not exceed		+260℃



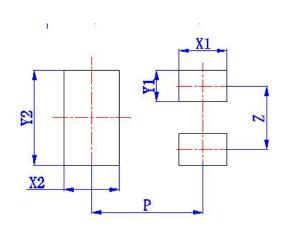


Package mechanical data



Cymbol	Millimeters		
Symbol	min	max	
А	0.4	0.5	
A1	0	0.05	
D	0.9	1.1	
E	0.55	0.65	
е	(0.35)		
e1	(0.65)		
b	0.2	0.3	
b1	0.2	0.3	
L	0.1	0.2	
L1	0.45 0.55		

Suggested Land Pattern



Symbol	Dimension in Millimeters	
Symbol	typ	
X1	(0.3)	
X2	(0.35)	
Y1	(0.2)	
Y2	(0.6)	
Z	(0.4)	
Р	(0.7)	

REEL SPECIFICATION

P/N	PKG	QTY
MMBT3904MB(MS)	DFN1006-3	10000



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